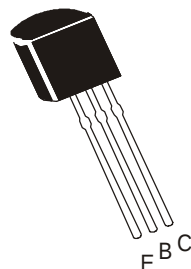


NPN SILICON PLANAR EPITAXIAL TRANSISTORS



MPSA44
MPSA45

TO-92
Plastic Package

High Voltage Transistors

Complementary of MPSA44 is MPSA94

ABSOLUTE MAXIMUM RATINGS

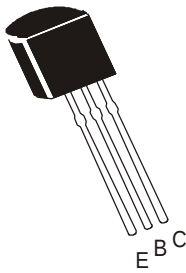
DESCRIPTION	SYMBOL	MPSA44	MPSA45	UNITS
Collector Base Voltage	V_{CBO}	500	400	V
Collector Emitter Voltage	V_{CEO}	400	350	V
Emitter Base Voltage	V_{EBO}	6.0		V
Collector Current	I_C	300		mA
Power Dissipation @ $T_a=25^\circ\text{C}$	P_D	625		mW
Derate Above 25°C		5.0		mW/ $^\circ\text{C}$
Power Dissipation @ $T_c=25^\circ\text{C}$	P_D	1.5		W
Derate Above 25°C		12		mW/ $^\circ\text{C}$
Operating And Storage Junction Temperature Range	T_j, T_{stg}	- 55 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Junction to Case	$R_{th(j-c)}$	83.3	$^\circ\text{C}$
Junction to Ambient in free air	$R_{th(j-a)}$	200	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$ MPSA44 MPSA45	400 350		V V
Collector Emitter Voltage	V_{CES}	$I_C=100\mu\text{A}, V_{BE}=0$ MPSA44 MPSA45	500 400		V V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$ MPSA44 MPSA45	500 400		V V
Emitter Base Voltage	V_{EBO}	$I_E=10\mu\text{A}, I_C=0$	6		V
Collector Cut Of Current	I_{CBO}	$V_{CB}=400\text{V}, I_E=0, \text{MPSA44}$ $V_{CB}=320\text{V}, I_E=0, \text{MPSA45}$		100 100	nA nA
Collector Cut Off Current	I_{CES}	$V_{CE}=400\text{V}, V_{BE}=0, \text{MPSA44}$ $V_{CE}=320\text{V}, V_{BE}=0, \text{MPSA45}$		500 500	nA nA
Emitter Cut off Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0$		100	nA



ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

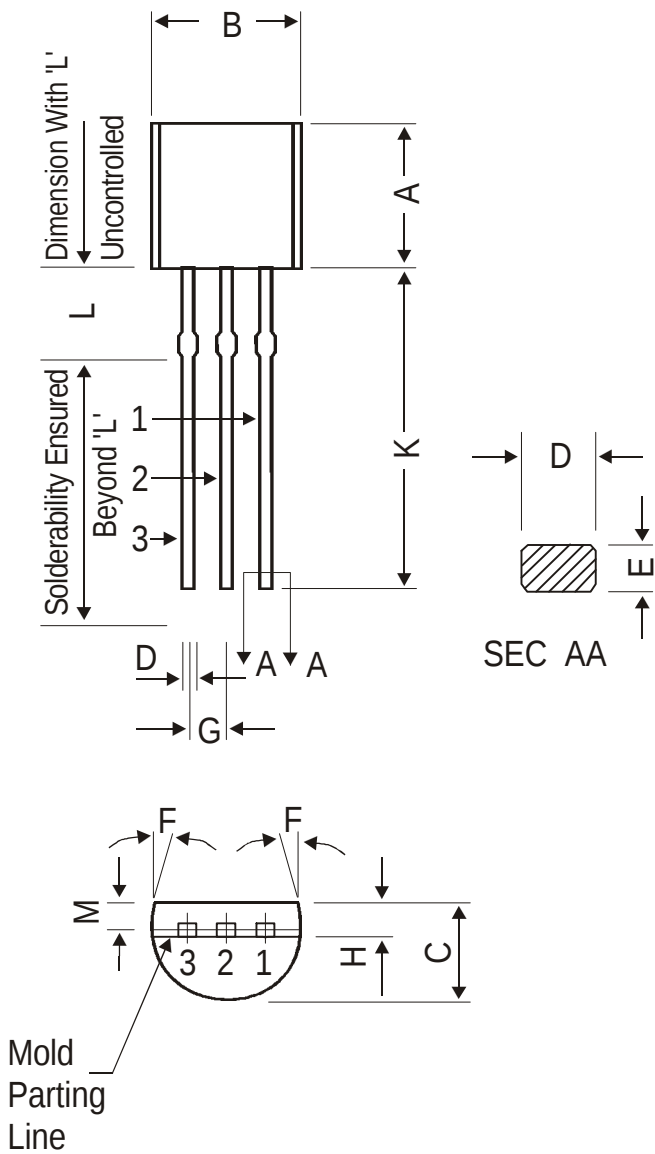
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
DC Current Gain	*h _{FE}	V _{CE} =10V, I _C =1mA	40	200	
		V _{CE} =10V, I _C =10mA	50		
		V _{CE} =10V, I _C =50mA	45		
		V _{CE} =10V, I _C =100mA	40		
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =1mA, I _B =0.1mA		0.40	V
		I _C =10mA, I _B =1mA		0.50	V
		I _C =50mA, I _B =5mA		0.75	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =10mA, I _B =1mA		0.75	V

DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Output Capacitance	C _{obo}	V _{CB} =20V, I _E =0, f=1MHz		7	pF
Input Capacitance	C _{ibo}	V _{EB} =0.5V, I _C =0, f=1MHz		130	pF
Small Signal Current Gain	h _{fe}	I _C =10mA, V _{CE} =10V, f=10MHz	2		

*Pulse test: Pulse Width ≤300ms, Duty Cycle≤2%

TO-92 Plastic Package

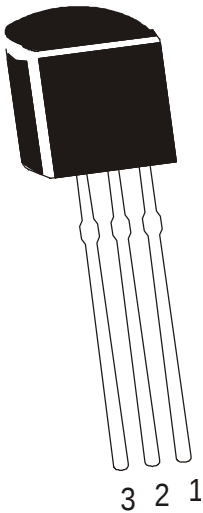


DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.20	1.40
K	12.70	—
L	1.982	2.082
M	1.03	1.20

All dimensions are in mm

PIN CONFIGURATION

- COLLECTOR
- BASE
- EMITTER



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

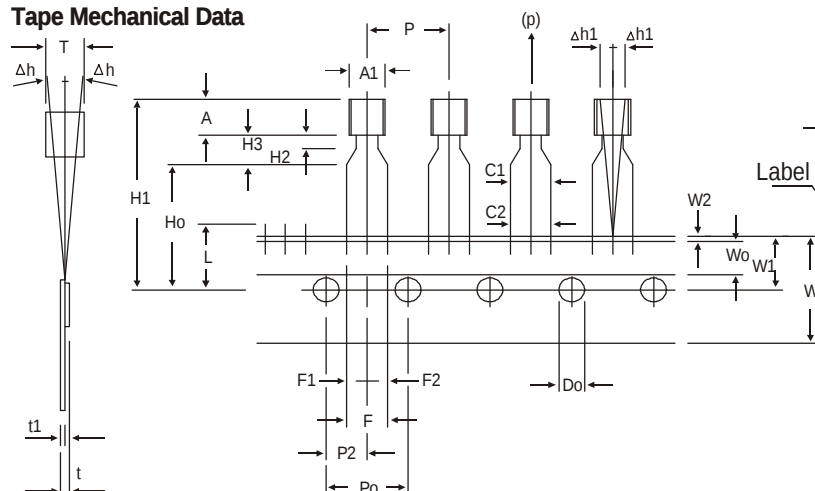
The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

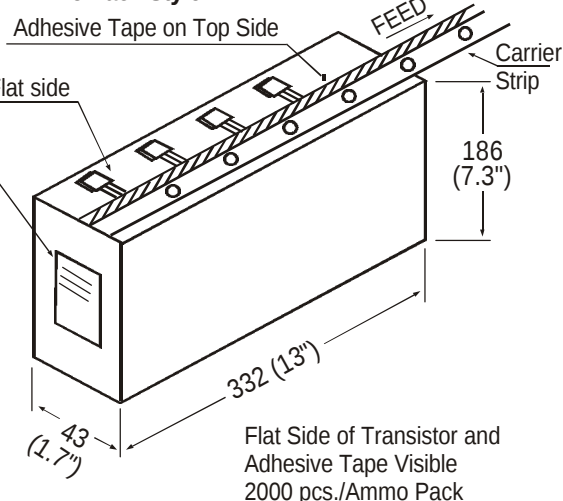
PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bul k	1K/polybag	200 gm /1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm /2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Tape and Ammo Pack

Tape Mechanical Data



Ammo Pack Style



All dimensions are in mm

ITEM	SYMBOL	SPECIFICATION			
		MIN.	NOM.	MAX.	TOL .
BODY WIDTH	A1	4.0		4.8	
BODY HEIGHT	A	4.8		5.2	
BODY THICKNESS	T	3.9		4.2	
PITCH OF COMPONENT	P		12.7		± 1.0
*1 FEED HOLE PITCH	Po		12.7		± 0.3
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6 - 0.2
*3 COMPONENT ALIGNMENT SIDE VIEW	Δh		0	1.0	
*4 COMPONENT ALIGNMENT FRONT VIEW	Δh1		0	1.3	
TAPE WIDTH	W		18		± 0.5
HOLD-DOWN TAPE WIDTH	W0		6		± 0.2
HOLE POSITION	W1		9		+ 0.7 - 0.5
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5
COMPONENT HEIGHT	H1			23.25	
LENGTH OF SNIPPED LEADS	L			11.0	
FEED HOLE DIAMETER	Do		4		± 0.2
*5 TOTAL TAPE THICKNESS	t			1.2	
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4 - 0.1
STAND OFF	H2	0.45		1.45	
CLINCH HEIGHT	H3			3.0	
LEAD PARALLELISM	C1 - C2			0.22	
PULL - OUT FORCE	(p)	6N			

NOTES

1. Maximum alignment deviation between leads will not to be greater than 0.2mm.
2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
4. There will be no more than three (3) consecutive missing components in a tape.
5. A tape trailer, having at least three feed holes are provided after the last component in a tape.
6. Splices should not interfere with the sprocket feed holes.

REMARKS

- *1 Cumulative pitch error 1.0 mm/20 pitch
- *2 To be measured at bottom of clinch
- *3 At top of body
- *4 At top of body
- *5 t1 0.3 – 0.6 mm

Disclaimer

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